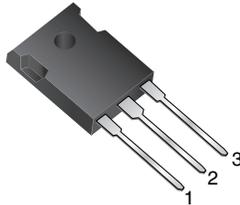


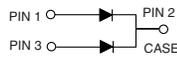


Dual Common-Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



TO-247AD (TO-3P)



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	40 A
V_{RRM}	35 V to 60 V
I_{FSM}	400 A
V_F	0.55 V, 0.60 V
$T_J \text{ max.}$	175 °C

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked**Mounting Torque:** 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR40H35PT	MBR40H45PT	MBR40H50PT	MBR40H60PT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Maximum working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Maximum average forward rectified current (Fig. 1)	$I_{F(AV)}$	40				A
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4\text{ A}$, $L = 10\text{ mH}$	E_{AS}	80				mJ
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	400				A
Peak repetitive reverse surge current per diode ⁽¹⁾	I_{RRM}	2.0		1.0		A
Peak non-repetitive reverse energy (8/20 μs waveform)	E_{RSM}	30		25		mJ
Electrostatic discharge capacitor voltage human body model: $C = 100\text{ pF}$, $R = 1.5\text{ k}\Omega$	V_C	25				kV
Voltage rate of change at (rated V_R)	dV/dt	10 000				V/ μs
Operating junction temperature range	T_J	- 65 to + 175				°C
Storage temperature range	T_{STG}	- 65 to + 175				°C

Note:(1) 2.0 μs pulse width, $f = 1.0\text{ kHz}$



ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR40H35PT MBR40H45PT		MBR40H50PT MBR40H60PT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 20 A	T _J = 25 °C	V _F	-	0.63	-	0.69	V
	I _F = 20 A	T _J = 125 °C		0.49	0.55	0.56	0.60	
	I _F = 40 A	T _J = 25 °C		-	0.73	-	0.83	
	I _F = 40 A	T _J = 125 °C		0.62	0.66	0.68	0.72	
Maximum reverse current at rated V _R per diode ⁽²⁾		T _J = 25 °C T _J = 125 °C	I _R	- 9.0	150 25	- 6.0	150 25	μA mA

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR40H35PT	MBR40H45PT	MBR40H50PT	MBR40H60PT	UNIT	
Thermal resistance, junction to case per diode	R _{θJC}	1.2					°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-247AD	MBR40H45PT-E3/45	6.13	45	30/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

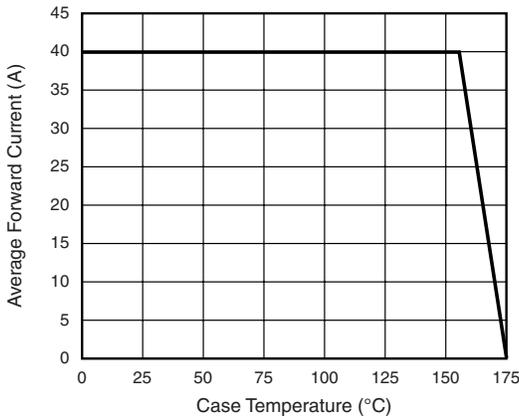


Figure 1. Forward Current Derating Curve

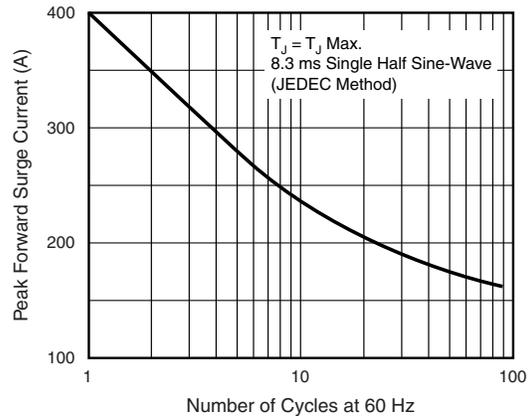


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



New Product
MBR40H35PT thru MBR40H60PT

Vishay General Semiconductor

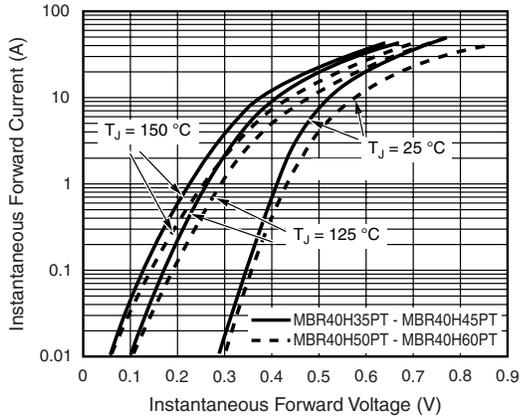


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

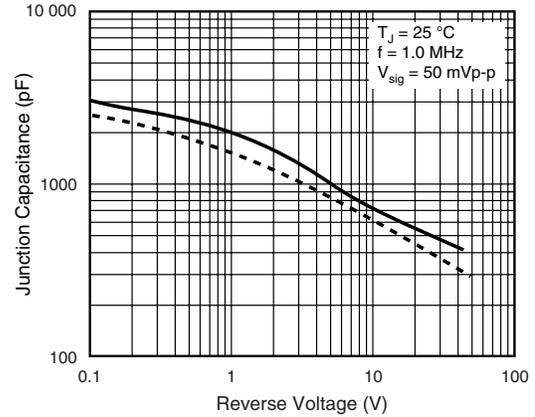


Figure 5. Typical Junction Capacitance Per Diode

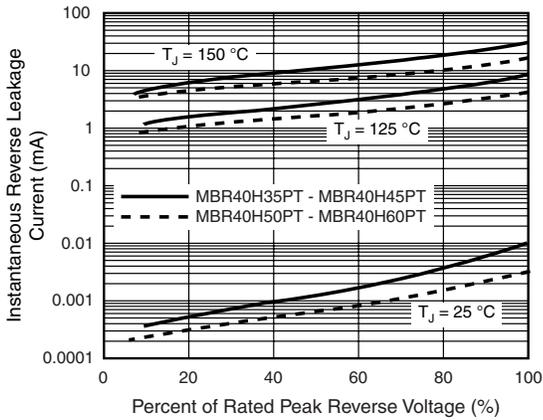


Figure 4. Typical Reverse Characteristics Per Diode

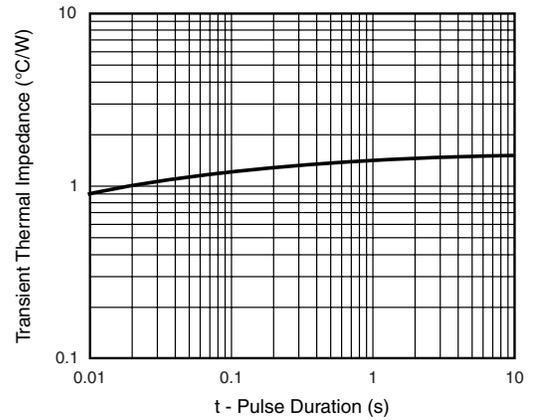
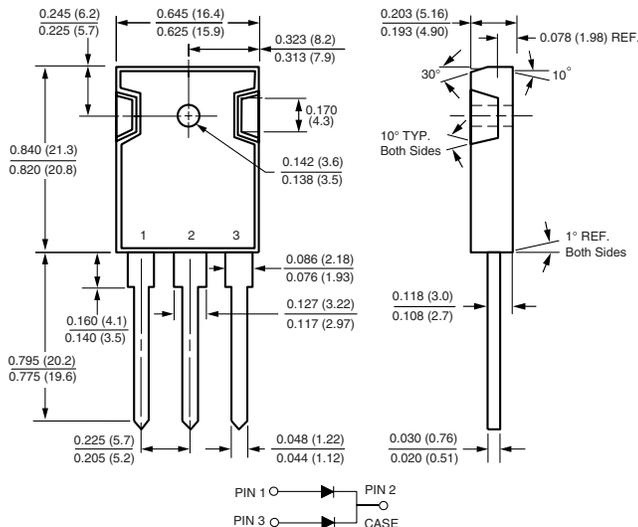


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)





Disclaimer

All product specifications and data are subject to change without notice.

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